

CMOS Analog Switches

DESCRIPTION

The DG300B, DG303B family of monolithic CMOS switches feature three switch configuration options (SPST, SPDT, and DPST) for precision applications in communications, instrumentation and process control, where low leakage switching combined with low power consumption are required.

Designed on the Vishay Siliconix PLUS-40 CMOS process, these switches are latch-up proof, and are designed to block up to 30 V peak-to-peak when off. An epitaxial layer prevents latchup.

In the on condition the switches conduct equally well in both directions (with no offset voltage) and minimize error conditions with their low on-resistance.

Featuring low power consumption (3.5 mW typ.) these switches are ideal for battery powered applications, without sacrificing switching speed. Designed for break-before-make switching action, these devices are CMOS and quasi TTL compatible. Single supply operation is allowed by connecting the V- rail to 0 V.

FEATURES

Analog signal range: ± 15 V

Fast switching - t_{ON}: 150 ns

Low on-resistance - R_{DS(on)}: 30 Ω

Single supply operation

· Latch-up proof

· CMOS compatible

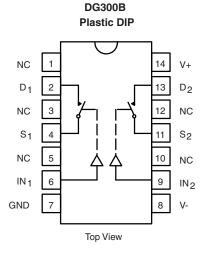
BENEFITS

- Full rail-to-rail analog signal range
- · Low signal error
- · Low power dissipation

APPLICATIONS

- Low level switching circuits
- · Programmable gain amplifiers
- · Portable and battery powered systems

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE					
Logic	Switch				
0	OFF				
1	ON				

Logic "0" ≤ 0.8 V Logic "1" ≥ 4 V

	DG301B Plastic DIP						
NC D ₁ NC	2		14 13	V+ D ₂ NC			
S ₁	4		11	S ₂			
NC	5	\downarrow	10	NC			
IN	6		9	NC			
GND	7		8	V-			
		Top View	•				

TRUTH TABLE						
Logic	SW ₁	SW ₂				
0	OFF	ON				
1	ON	OFF				

Logic "0" ≤ 0.8 V Logic "1" ≥ 4 V

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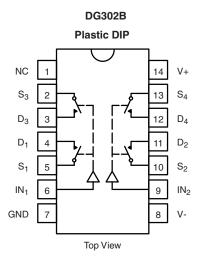
^{*} Pb containing terminations are not RoHS compliant, exemptions may apply.

DG300B, DG301B, DG302B, DG303B

Vishay Siliconix



FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



	DG303B					
	F	Plastic D	IP and	so	IC	
NC S_3 D_3 D_1 S_1 IN_1 GND	1 2 3 4 5 6			} 	14 13 12 11 10 9	V+ S ₄ D ₄ D ₂ S ₂ IN ₂ V-
		Тор	View			

TRUTH TABLE				
Logic	Switch			
0	OFF			
1	ON			

Logic "0" ≤ 0.8 V Logic "1" ≥ 4 V

TRUTH TABLE					
Logic SW ₁ , SW ₂ SW ₃ , SW ₄					
0	OFF	ON			
1	ON	OFF			

Logic "0" ≤ 0.8 V Logic "1" ≥ 4 V

ORDERING INFORMATION					
Temp. Range	Standard Package	Standard Part Number	Lead (Pb)-free Part Number		
		DG300BDJ	DG300BDJ-E3		
	14-Pin Plastic DIP	DG301BDJ	DG301BDJ-E3		
		DG302BDJ	DG302BDJ-E3		
- 40 °C to 85 °C		DG303BDJ	DG303BDJ-E3		
	14-SOIC	DG303BDY	DG303BDY-T1 DG303BDY-E3 DG303BDY-T1-E3		

Parameter		Limit	Unit
Voltages Referenced V+ to V-		44	
GND		25	V
Digital Inputs ^a , V _S , V _D		(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first	v
Current (Any Terminal)		30	mΛ
Continuous Current, S or D (Pulse	ed at 1 ms, 10 % duty cycle max.)	100	mA
Storage Temperature		- 65 to 150	°C
D	14-Pin PlasticDIP ^c	470	mW
Power Dissipation (Package) ^b	SOIC-14 ^d	600	IIIVV

Notes:

- $a. \ Signals \ on \ S_X, \ D_X, \ or \ IN_X \ exceeding \ V+ \ or \ V- \ will \ be \ clamped \ by \ internal \ diodes. \ Limit \ forward \ diode \ current \ to \ maximum \ current \ ratings.$
- b. All leads welded or soldered to PC board.
- c. Derate 6.5 mW/°C above 25 °C
- d. Derate 7.6 mW/°C above 75 °C.

SCHEMATIC DIAGRAM (Typical Channel)

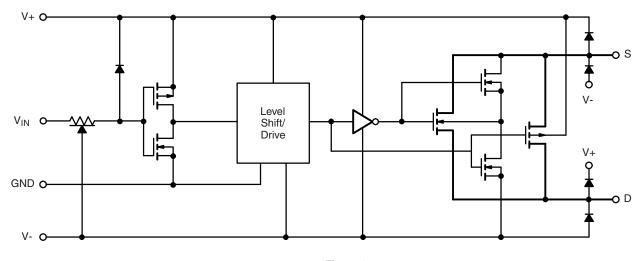


Figure 1.

DG300B, DG301B, DG302B, DG303B

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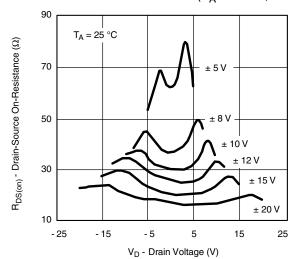
SPECIFICATIONS ^a								
		Test Condit Unless Otherwise V+ = 15 V, V- =	Specified		- 4	Limits 0 °C to 85	°C	
Parameter	Symbol	$V_{IN} = 0.8 \text{ V or V}$		Temp.b	Min. ^d	Typ. ^c	Max. ^d	Unit
Analog Switch				<u> </u>	l			l
Analog Signal Range ^e	V _{ANALOG}			Full	- 15		15	V
Drain-Source On-Resistance	R _{DS(on)}	$V_D = \pm 10 \text{ V}, I_S =$	- 10 mA	Room Full		30	50 75	Ω
Source Off Leakage Current	I _{S(off)}	$V_S = \pm 14 \text{ V}, V_D$	= + 14 V	Room Hot	- 5 - 100	± 0.1	5 100	
Drain Off Leakage Current	I _{D(off)}	•§ - ± · · •, • _D		Room Hot	- 5 - 100	± 0.1	5 100	nA
Drain On Leakage Current	I _{D(on)}	$V_S = V_D = \pm$	14 V	Room Hot	- 5 - 100	± 0.1	5 100	
Digital Control								
Input Current with	I _{INH} -	V _{IN} = 5 \	/	Room Full	- 1	- 0.001		
Input Voltage High	IINFI	V _{IN} = 15 V		Room Full		0.001	1	μΑ
Input Current with Input Voltage Low	I _{INL}	V _{IN} = 0 V		Room Full	- 1	- 0.001		
Dynamic Characteristics								
Turn-On Time	t _{ON}	see figure	2	Room		150		
Turn-Off Time	t _{OFF}			Room		130		ns
Break-Before-Make Time	t _{OPEN}	DG301B, DG30 figure 3	,	Room		50		
Charge Injection	Q	$C_L = 1 \text{ nF, } R_{gen} = 0.9$ figure 4		Room		8		рC
Source Off Capacitance	C _{S(off)}			Room		14		
Drain Off Capacitance	C _{D(off)}	$V_{S}, V_{D} = 0 V, f =$	= 1 MHz	Room		14		
Channel-On Capacitance	C _{D(on)}			Room		40		pF
Input Capacitance	C _{in}	f = 1 MHz	$V_{IN} = 0 V$	Room		6		
при Сараспансе	O _{In}		V _{IN} = 15 V	Room		7		
Off Isolation	OIRR	V _{IN} = 0 V, R _L =		Room		62		dB
Crosstalk (Channel-to-Channel)	X _{TALK}	$V_S = 1 V_{rms}$, $f =$	500 kHz	Room		74		UD
Power Supplies								
Positive Supply Current	l+	V _{IN} = 4 V (one input)		Room Full		0.23	1	mA
Negative Supply Current	l-	all others =	0 V	Room Full	- 100	- 0.001		
Positive Supply Current	l+	V _{IN} = 0.8 V (all	inputs)	Room Full		0.001	100	μΑ
Negative Supply Current	l-	- 111	,,,	Room Full	- 100	- 0.001		

Notes:

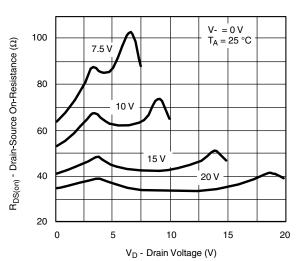
- a. Refer to PROCESS OPTION FLOWCHART.
- b. Room = 25 °C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e. Guaranteed by design, not subject to production test.
- f. V_{IN} = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

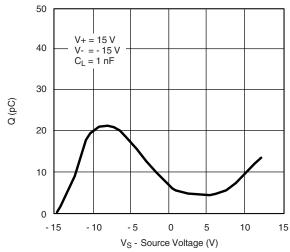
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



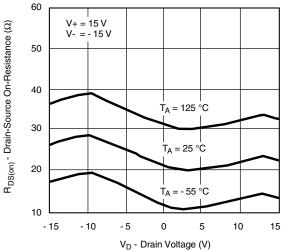
 $R_{DS(on)}$ vs. V_D and Power Supply



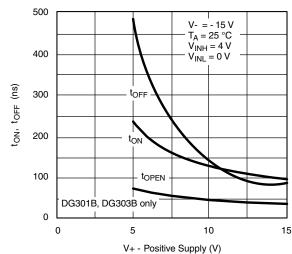
 $R_{DS(on)}$ vs. V_D and Power Supply Voltage



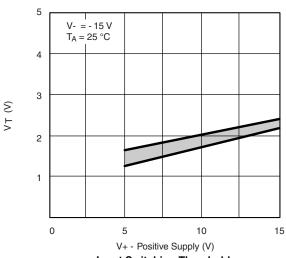
Charge Injection vs. Analog Voltage



R_{DS(on)} vs. V_D and Temperature



Switching Time and Break-Before-Make Time vs. Positive Supply Voltage

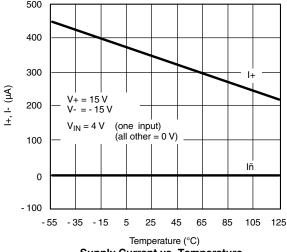


DG300B, DG301B, DG302B, DG303B

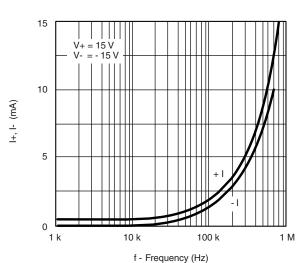
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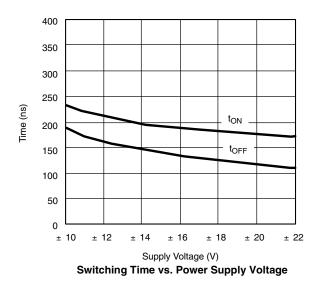
TYPICAL CHARACTERISTICS ($T_A = 25$ °C, unless otherwise noted)



Supply Current vs. Temperature

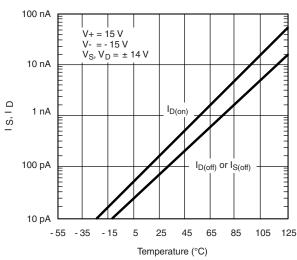


Supply Curents vs. Switching Frequency

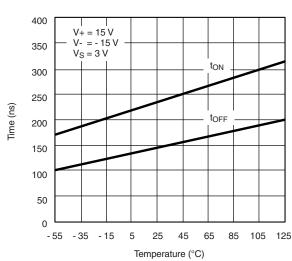


-120 -80 -80 -40 -40 -100

Off Isolation and Crosstalk vs. Frequency



Leakage vs. Temperature



Switching Time vs. Temperature

TEST CIRCUITS

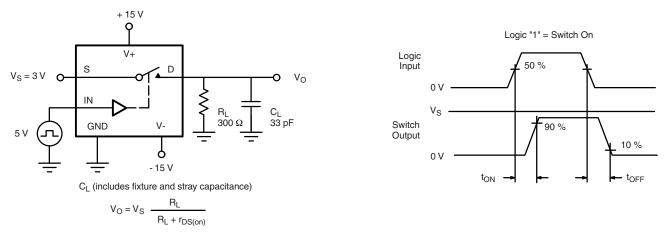


Figure 2. Switching Time

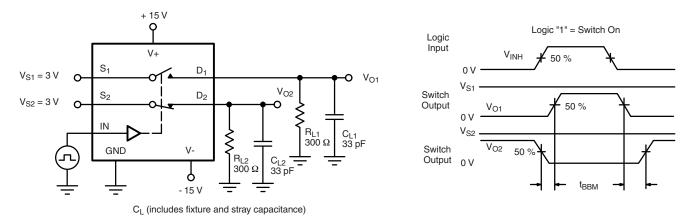


Figure 3. Break-Before-Make SPDT (DG301B, DG303B)

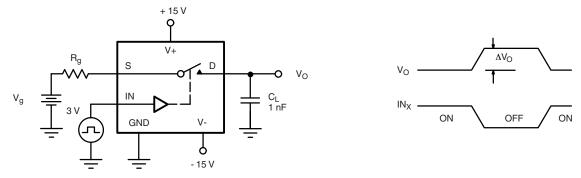


Figure 4. Charge Injection



APPLICATIONS H	APPLICATIONS HINTS ^a						
V+ Positive Supply Voltage (V)	V- Negative Supply Voltage (V)	GND Voltage (V)	V _{IN} Logic Input Voltage V _{INH(min)} /V _{INL(max)} (V)	V _S or V _D Analog Voltage Range (V)			
15	- 15	0	4/0.8	- 15 to 15			
20	- 20	0	4/0.8	- 20 to 20			
15	0	0	4/0.8	0 to 15			

Notes:

APPLICATIONS

The DG300B series of analog switches will switch positive analog signals while using a single positive supply. This facilitates their use in applications where only one supply is available. The trade-offs of using single supplies are:

- 1) Increased R_{DS(on)}.
- 2) Slower switching speed. The analog voltage should not go above or below the supply voltages which in single operation are V+ and 0 V. (See Input Switching Threshold vs. Positive Supply Voltage Curve.)

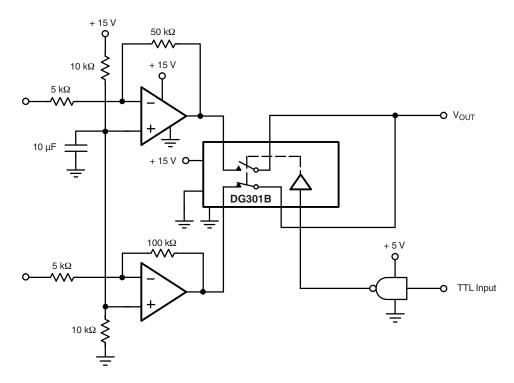


Figure 5. Single Supply Op. Amp. Switching

a. Application hints are for DESIGN AID ONLY, not guaranteed and not subject to production testing.

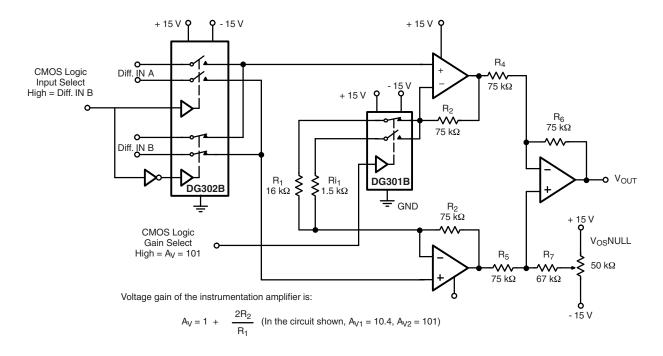
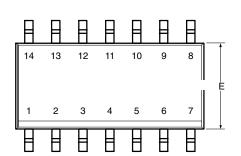


Figure 6. Low Power Instrumentation Amplifier with Digitally Selectable Inputs and Gain

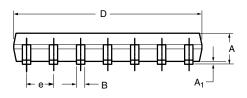
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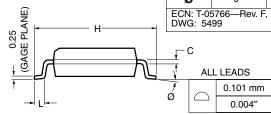


SOIC (NARROW): 14-LEAD



	MILLIMETERS		INC	HES	
Dim	Min	Max	Min	Max	
Α	1.35	1.75	0.053	0.069	
A ₁	0.10	0.20	0.004	0.008	
В	0.38	0.51	0.015	0.020	
С	0.18	0.23	0.007	0.009	
D	8.55	8.75	0.336	0.344	
Е	3.8	4.00	0.149	0.157	
е	1.27	BSC	0.050	BSC	
Н	5.80	6.20	0.228	0.244	
L	0.50	0.93	0.020	0.037	
Ø	0°	8°	0°	8°	
ECN: T-05766—Rev. F, 19-Sep-05					





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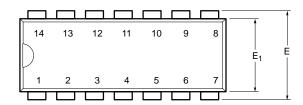
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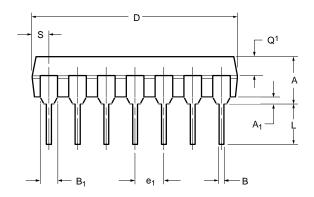
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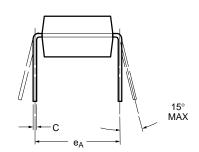
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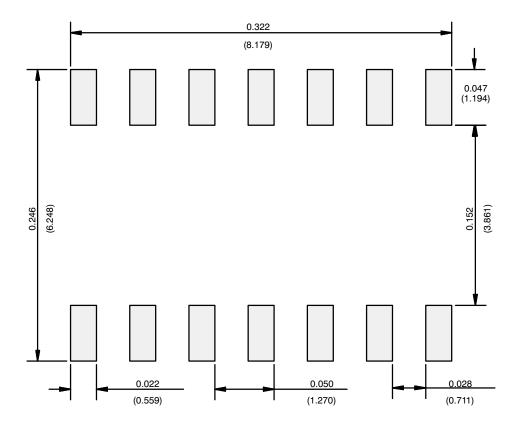


	MILLIN	METERS	INC	HES	
Dim	Min	Max	Min	Max	
Α	3.81	5.08	0.150	0.200	
A ₁	0.38	1.27	0.015	0.050	
В	0.38	0.51	0.015	0.020	
B ₁	0.89	1.65	0.035	0.065	
С	0.20	0.30	0.008	0.012	
D	17.27	19.30	0.680	0.760	
Е	7.62	8.26	0.300	0.325	
E ₁	5.59	7.11	0.220	0.280	
e ₁	2.29	2.79	0.090	0.110	
e _A	7.37	7.87	0.290	0.310	
L	2.79	3.81	0.110	0.150	
Q_1	1.27	2.03	0.050	0.080	
S	1.02	2.03	0.040	0.080	
ECN: S-03946—Rev. C, 09-Jul-01 DWG: 5481					

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RECOMMENDED MINIMUM PADS FOR SO-14



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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